

Mechanochemical synthesis of MgTa_2O_6 ceramic

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Abstract

MgTa_2O_6 powders were prepared by mechanochemical synthesis from MgO and Ta_2O_5 in a planetary ball mill in air atmosphere using steel vial and steel balls. High-energy ball milling gave nearly single-phase MgTa_2O_6 after 8 h of milling time. Annealing of high-energy milled powder at various temperatures (700–1200 °C) indicated that high-energy milling speed up the formation and crystallization of MgTa_2O_6 from the amorphous mixture. The powder derived from 8 h of mechanical activation gave a particle size of around 28 nm. Although at low-annealing temperatures the grain size was almost the same as-milled powder, the grain size increased with annealing temperature reaching to around 1–2 μm after annealing at 1200 °C for 8 h.

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1. Introduction

The dielectric ceramics at microwave frequency have been paid much attention for their applications in microwave resonators, filters, antennas and wave guides due to rapid progress of mobile and satellite communication systems such as cellular phones and global positioning satellite devices. These applications require a combination of high-dielectric permittivity ($\epsilon_r > 15$), near zero temperature coefficient of resonant frequency (τ_f) and high-quality factor (Q). A higher permittivity value enables the resonator size to be reduced [1]. A very small temperature coefficient of resonant frequency (less than ± 10 ppm/°C) is necessary for the stability of the device at room temperature. The quality factor of dielectric resonators determines their frequency selectivity.

Niobium and tantalum-based oxides such as $\text{Ba}_3\text{MgNb}_2\text{O}_9$, $\text{Ba}_3\text{MgTa}_2\text{O}_9$ and $\text{Ba}_3\text{ZnTa}_2\text{O}_9$ are good candidates for dielectric resonators at microwave frequencies [2,3]. Complex perovskite compounds with general formula of $\text{A}(\text{B}_{1/3}\text{B}'_{2/3})\text{O}_3$ such as $\text{Ba}(\text{Mg}_{1/3}\text{Ta}_{2/3})\text{O}_3$, $\text{Ba}(\text{Zn}_{1/3}\text{Ta}_{2/3})\text{O}_3$ and $\text{Ba}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ are also known to possess high-dielectric microwave properties [4,5]. In addition, in a recent study excellent microwave dielectric properties were obtained for $\text{Ba}[\text{Mg}_{1/3}$

$3(\text{Nb}_{x/4}\text{Ta}_{(4-x)/4})_{2/3}] \text{O}_3$ compound ($x = 1$) where Nb and Ta form solid solution [6]. Another type of oxides that contain Nb or Ta and are investigated for their microwave dielectric properties are AB_2O_6 compounds ($\text{A} = \text{Ca}, \text{Mg}, \text{Mn}, \text{Co}, \text{Ni}, \text{Zn}$; $\text{B} = \text{Nb}$ and Ta) which have columbite or trirutile structure [7,8].

MgTa_2O_6 has trirutile structure and it has applications as microwave dielectric materials due to its dielectric properties. MgTa_2O_6 has a dielectric constant in the range of 25–30, quality factor of 28,500–58,000 and temperature coefficient of resonant frequency of 22–28.5 depending on the sintering temperatures of 1400–1550 °C.

In this study, MgTa_2O_6 ceramic was produced using mechanochemical synthesis. Effect of milling time and annealing temperature on the formation of MgTa_2O_6 was investigated in detail. Produced powders were examined using X-ray diffraction and scanning electron microscopy.

2. Experimental

Starting reagents were $\text{Mg}(\text{OH})_2$ (Merck, 99.8%) and Ta_2O_5 (Merck, 99.9%) with nominal composition of MgTa_2O_6 . $\text{Mg}(\text{OH})_2$ was converted to MgO at 1200 °C prior to use. The high-energy ball milling was carried out in a planetary ball mill (Fritsch Pulverisette 5) under following milling conditions: stainless steel vial (500 ml) and balls (10 mm in diameter), ball-to-powder ratio was 40:1, air atmosphere, rotation speed of

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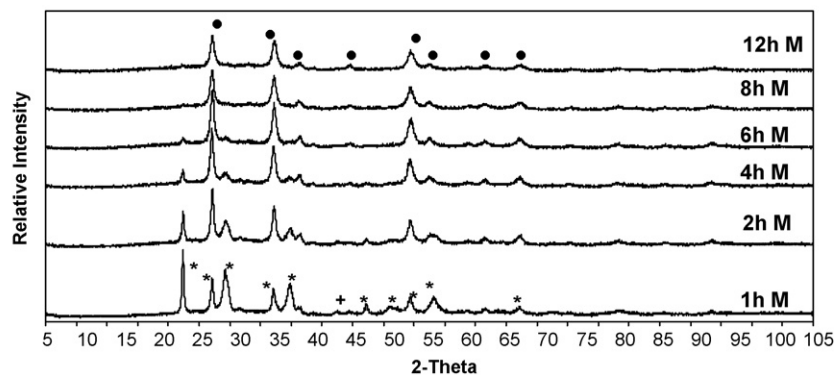


Fig. 1. Effect of milling time on the formation of MgTa_2O_6 phase in mechanochemical synthesis after high-energy milling of 1, 2, 4, 6, 8 and 12 h (* tantalum oxide; '+' MgO; '●' MgTa_2O_6).

discs with vials was 280 min^{-1} and milling time was 1, 2, 3, 4, 8 and 12 h. The milled powder was annealed for 8 h at temperatures from 900 to 1200°C in air.

Phase composition of the milled and annealed powders was determined by X-ray powder diffraction analysis (XRD) on Rigaku powder diffractometer using $\text{Cu K}\alpha$ radiation. The average crystallite size of the milled powder was estimated

using the Scherrer formula [9]:

$$D = \frac{k\lambda}{B \cos \theta}$$

where D is the mean particle size (nm), k a constant (taken as 0.9), $\lambda = 0.15406$, the wavelength of $\text{Cu K}\alpha$, B the full width at

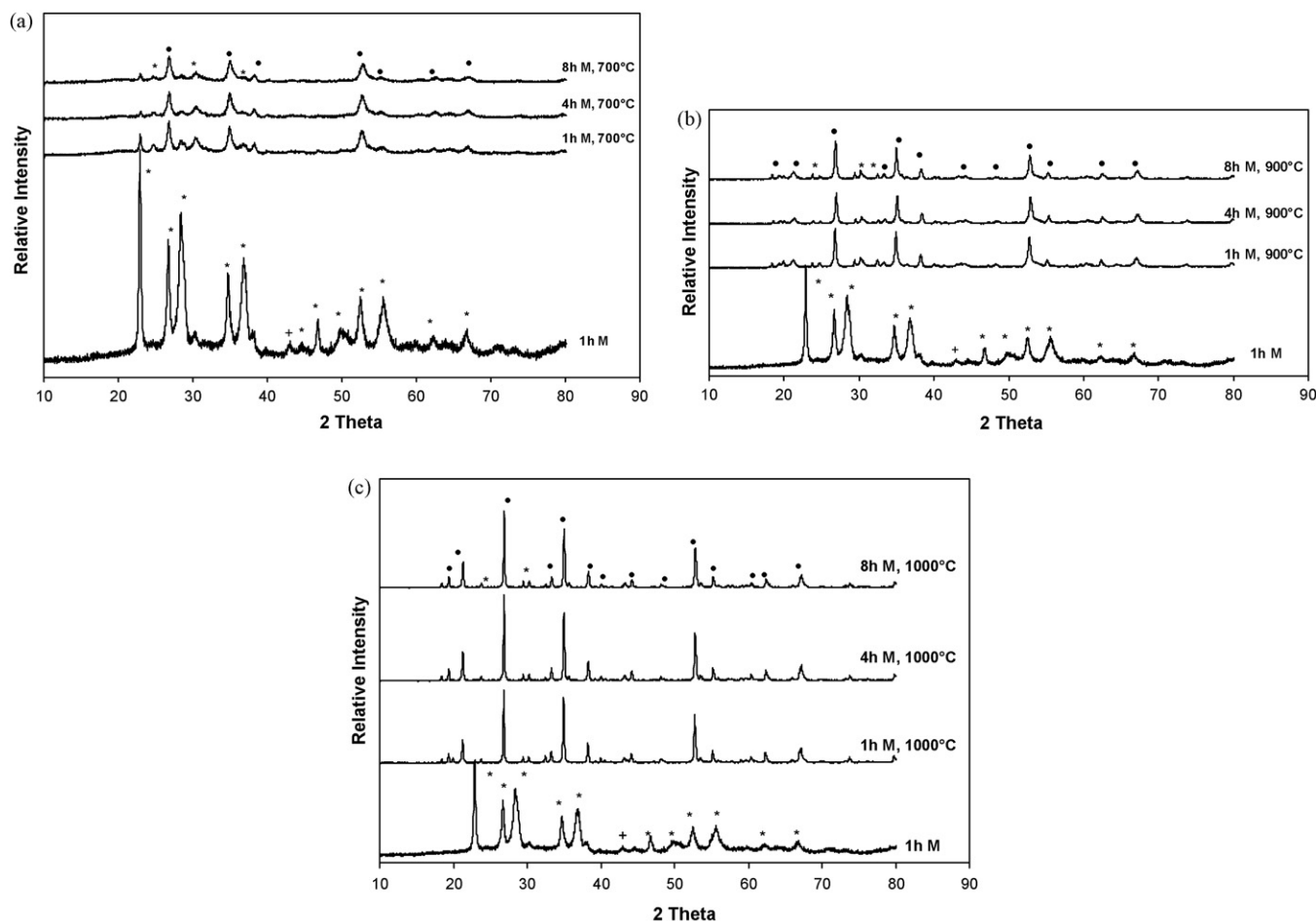


Fig. 2. Phase development in powders milled for 1 h, 4 h and 8 h and heat treated for 1, 4 and 8 h: (a) 700°C , (b) 900°C and (c) 1000°C (* tantalum oxide; '+' MgO; '●' MgTa_2O_6).

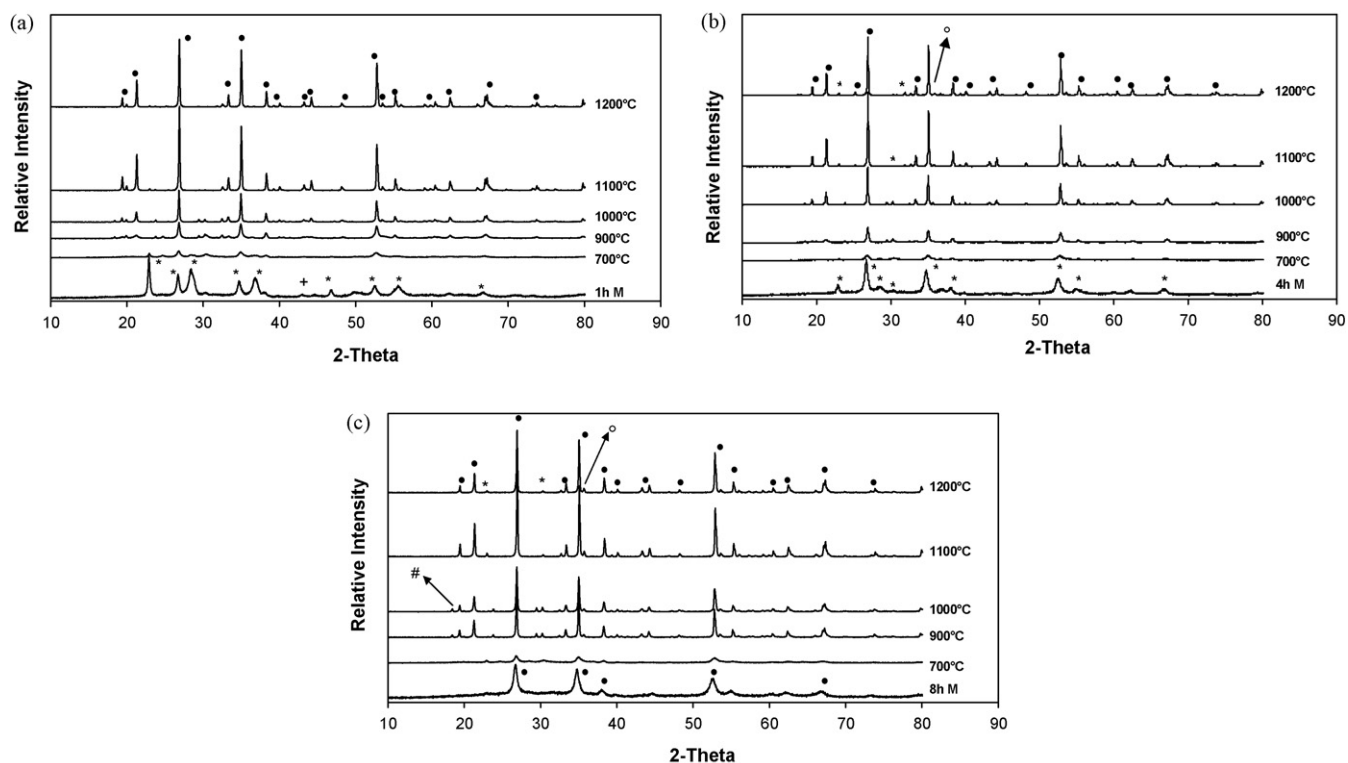


Fig. 3. Effect of annealing temperature on the phase development of powders milled for 1, 4 and 8 h and annealed at (a) 700 °C, (b) 900 °C and (c) 1000 °C (*' tantalum oxide; '+' MgO; '●' MgTa₂O₆; '#' unidentified peak; '○' iron oxide).

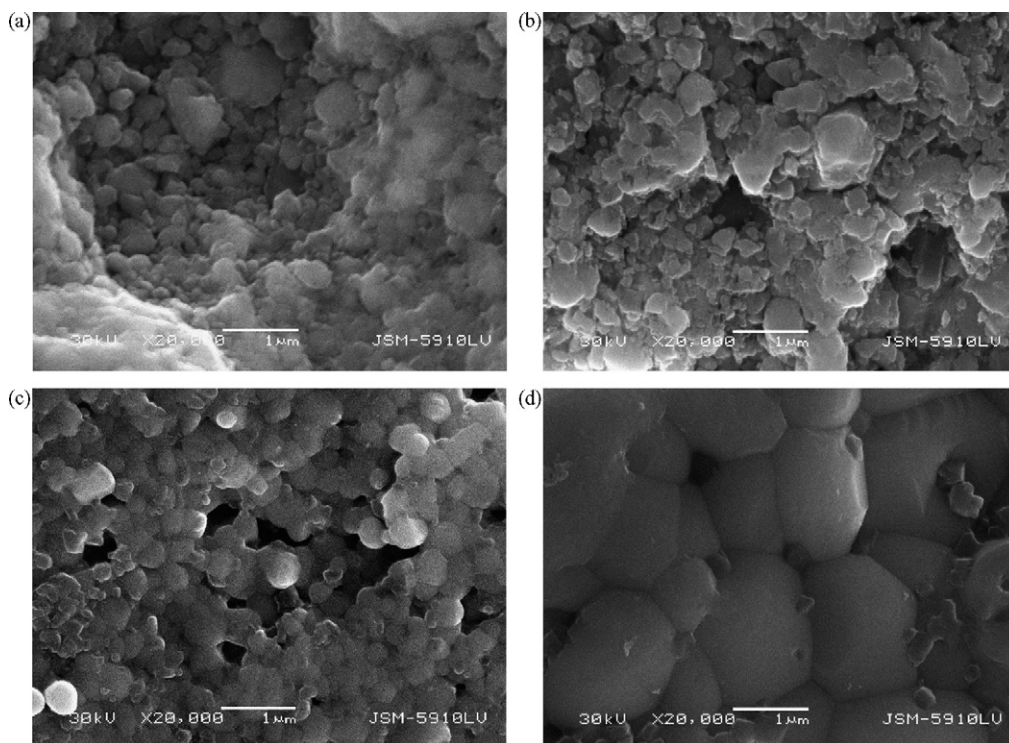


Fig. 4. Scanning electron micrographs of 8 h milled powders annealed for 8 h at various temperatures: (a) 8 h milled powder without annealing, (b) powder annealed at 700 °C, (c) powder annealed at 1000 °C and (d) powder annealed at 1200 °C.

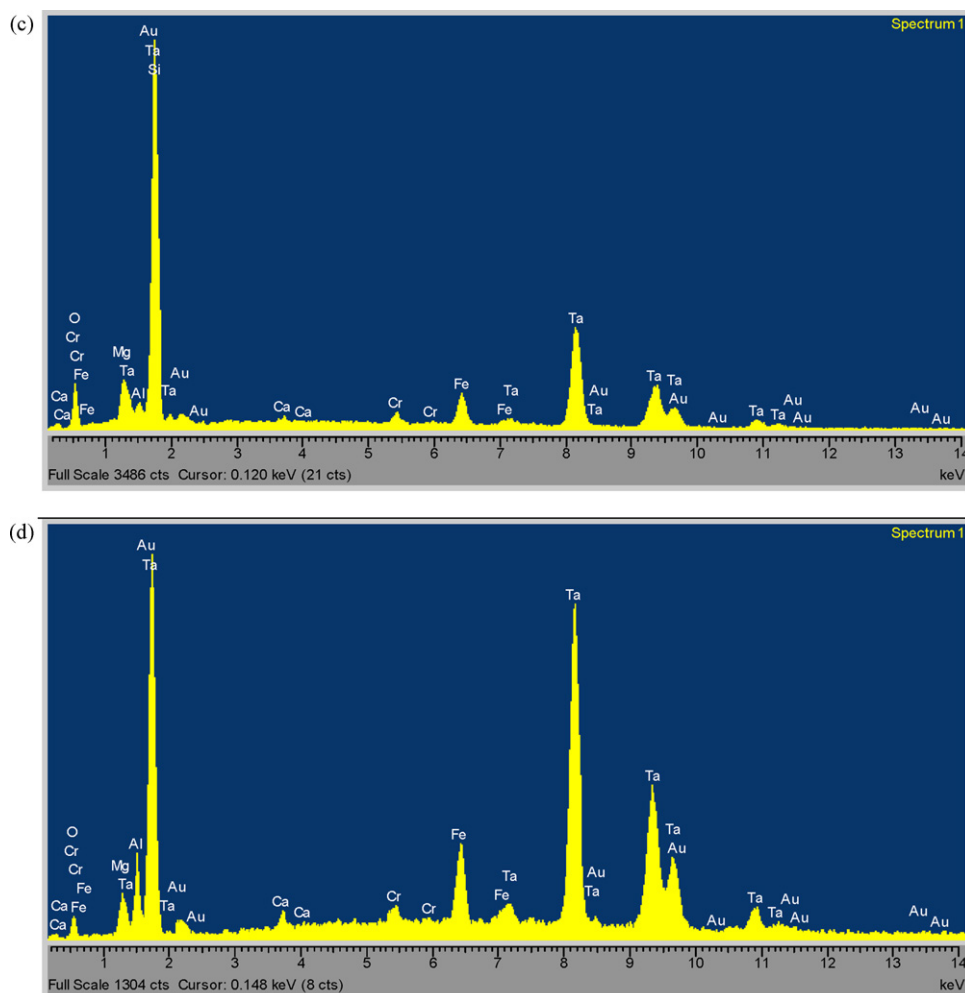


Fig. 5. (Continued).

In order to clearly indicate the effect of temperature on the phase development and on the crystallization of MgTa_2O_6 , powders fabricated by mechanochemical synthesis annealed between 700 and 1200 °C for 8 h. In powders milled for 1 h, although MgTa_2O_6 was the predominant phase, some peaks belong to tantalum oxide were also identified (Fig. 3a). As the temperature increased the intensity of tantalum oxide peaks decreased while the intensity of MgTa_2O_6 increased. At 1200 °C, nearly pure MgTa_2O_6 phase was obtained. In terms of crystallinity, at 700 °C the powders were mostly amorphous in nature and the crystallinity increased with temperature. At 1100 °C, all the peaks were sharp indicating possibly no any amorphous phase was left and also an increase in the particle size of MgTa_2O_6 powders. For powders milled for 4 and 8 h, no single MgTa_2O_6 phases was obtained even at 1200 °C and there were additional tantalum oxide peaks (Fig. 3b and c). At low temperatures, the tantalum oxide peaks were high in intensity and the intensities decreased with temperature. But even at high temperatures of 1200 °C, all the tantalum oxide did not convert to MgTa_2O_6 . In addition, an unidentified peak was appeared at 900 °C and disappeared at 1100 °C in powders milled for 4 and 8 h (Fig. 3b and c). Iron oxide peak (at about 38°) was also observed in powders milled for 4 and 8 h due to contamination

effect (Fig. 3b and c) but no any iron impurity was observed in powders milled for 1 h (Fig. 3a). Although the iron oxide content was very low, its amount increased as the milling time increased.

Fig. 3 also clearly indicated that milling time had a significant effect on the crystallinity of MgTa_2O_6 phase. Although high crystallinity was obtained at 1000 °C for powder milled for 1 and 4 h, it was obtained at 900 °C for powders milled for 8 h.

Micrographs of scanning electron microscopy of the milled powders before and after annealing between 700 and 1200 °C for 8 h are shown in Fig. 4. Although at low-annealing temperatures the grain size was almost the same as-milled powder, the grain size increased with annealing temperature. The size of the sub-micron particles obtained from milling for 8 h before annealing reached to around 200–500 nm and 1–2 μm after annealing at 1000 and 1200 °C, respectively.

Scanning electron microscopy investigation also revealed various phases in the microstructure (Fig. 5). Fig. 5a gives the backscattered electron images of as-milled powders that indicate three different phases. Fe-rich phase was observed in the microstructure (region A in Fig. 5a) as it was observed in XRD pattern (Fig. 3b). This was due to contamination during

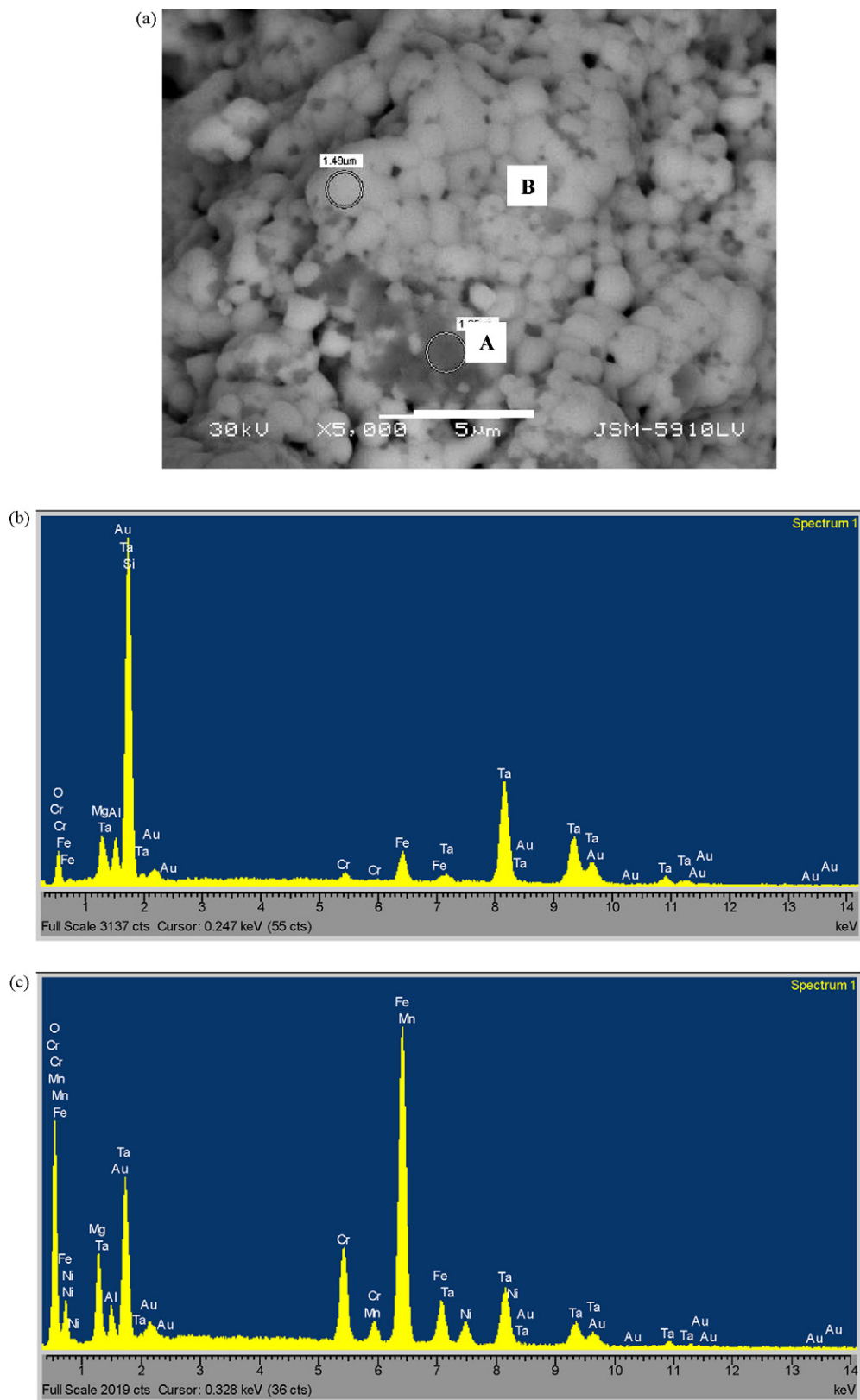


Fig. 6. Backscattered electron images and EDS analysis of powders milled for 8 h and annealed at 1200 °C for 8 h: (a) backscattered electron micrograph, (b) EDS analysis of MgTa_2O_6 phase (region A) and (c) EDS analysis of Fe-rich phase (region B).

milling. In addition, MgTa_2O_6 (region B in Fig. 5b) and a Ta-rich phase (region C in Fig. 5b) were also identified. Microstructural investigation also indicated that the amount of Ta-rich phase decreased significantly in samples annealed at 1200 °C for 8 h (Fig. 6).

4. Conclusions

The mechanochemical synthesis was successfully used to produce nanostructure MgTa_2O_6 powders from stoichiometric MgO and Ta_2O_5 mixtures. Nearly single phase MgTa_2O_6 was obtained after milling for 8 h with particle size of around 28 nm. High-energy milling increased the reactivity of milled powders which promote the formation of MgTa_2O_6 phase at lower temperatures. Milling time had a significant effect on the crystallinity of MgTa_2O_6 phase during annealing. Low-temperature annealing did not have almost any effect on the grain growth but increasing annealing temperature significantly increased the MgTa_2O_6 grain size. Scanning electron microscopy investigation also indicated Fe-rich phase due to contamination during milling and Ta-rich phase due to unreacted tantalum oxide in addition to MgTa_2O_6 phase.

References

- [1] M.P. Seabra, M. Avdeev, V.M. Ferreira, P.C. Pullar, N.McN. Alford, Structure and microwave dielectric properties of $\text{La}(\text{Mg}_{0.5}\text{Ti}_{0.5})\text{O}_3\text{--CaTiO}_3$ system, *J. Eur. Ceram. Soc.* 23 (2003) 2403–2408.
- [2] S. Nomura, T. Toyama, K. Kaneta, $\text{Ba}(\text{Mg}_{1/3}\text{Ta}_{2/3})\text{O}_3$ ceramics with temperature stable high dielectric constant and low microwave loss, *Jpn. J. Appl. Phys.* 21 (1982) L624–L626.
- [3] S. Kawashima, M. Nishida, I. Ueda, H. Ouchi, $\text{Ba}(\text{Zn}_{1/3}\text{Ta}_{2/3})\text{O}_3$ ceramics with low dielectric loss at microwave frequencies, *J. Am. Ceram. Soc.* 66 (1983) 421–423.
- [4] J. Shimada, Dielectric loss and damping constants of lattice vibrations in $\text{Ba}(\text{Mg}_{1/3}, \text{Ta}_{2/3})\text{O}_3$ ceramics, *J. Eur. Ceram. Soc.* 23 (2003) 2647–2651.
- [5] S. Nomura, Ceramics for microwave dielectric resonator, *Ferroelectrics* 49 (1983) 61–70.
- [6] C.F. Lin, H.H. Lu, T.I. Chang, J.L. Huang, Microstructural characteristics and microwave dielectric properties of $\text{Ba}[\text{Mg}_{1/3}(\text{Nb}_{x/4}\text{Ta}_{(4-x)/4})_{2/3}]\text{O}_3$ ceramics, *J. Alloys Compd.* 407 (2006) 318–325.
- [7] M. Maeda, T. Yamamura, T. Ikeda, Dielectric characteristics of several complex oxide ceramics at microwave frequencies, *Jpn. J. Appl. Phys. Suppl.* 26 (1987) 76–79.
- [8] H.J. Lee, K.S. Hong, S.J. Kim, I.T. Kim, Dielectric properties of MnB_2O_6 compounds (where M = Ca, Mn, Co, Ni, or Zn), *Mater. Res. Bull.* 32 (1997) 847–855.
- [9] B.D. Cullity, S.R. Stock, *Elements of X-Ray Diffraction*, Prentice Hall, USA, 2001.